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Origin of superconductivity transition broadening in MgB_2

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Abstract

We report resistivity and magnetization of single crystal MgB_2, focusing on the broadening of superconducting (SC) transition in magnetic fields. In-plane and out-of-plane resistivity indicate that the broadening of superconducting transition is independent of Lorentz force and that it is merely dependent on the magnetic field direction. In magnetization, diamagnetic signal begins to appear at almost the same temperature as the onset temperature of resistivity transition. These results suggest that the broadening is attributed not to the surface superconductivity but to the superconducting fluctuation or the vortex-liquid picture, owing to the short coherence length and the high transition temperature of MgB_2.

Key words: MgB_2, Resistivity, Critical field, Anisotropy
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1 Introduction

Since the discovery of superconductivity in MgB_2 [1], the upper critical fields have been one of the main interests. After succeeding in crystal growth [2,3,4,5], the anisotropy of critical field has been investigated by many research groups [2,3,4], since relatively large anisotropy was expected from the layered crystal structure. The anisotropy of H_{c2} has been determined through the resistivity measurements, followed by specific heat and torque magnetometry measurements [6,7]. Since a superconductivity transition in resistivity broadens in

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magnetic fields, critical temperature (T_c) has been determined from the onset temperature $T_{on,\rho}$, where resistivity starts to drop. The obtained anisotropy ratio $H_{c2}^{ab}//H_{c2}^{c}$ of about 3 at 25 K is in good agreement among the reports [2,3,4,8]. However, contrary to the resistivity results, an ESR study first indicated much larger anisotropy ratio of 6-9 [9]. One of the origins for this discrepancy in anisotropy ratio is the uncertainty of the T_c determination, owing to the broadening in magnetic fields. Actually, if T_c is determined by the temperature T_0 where resistivity vanishes, the higher anisotropy ratio of about 5 is obtained. This casts a question what is the physical meaning of the onset temperature T_{on}.

As to the resistive broadening, many explanations have been proposed; glassy state of vortices [10,11,12], surface superconductivity related to H_{c3} [7], and two superconductivity gap effect [12]. In the report of surface superconductivity [7] magnetization data played a critical role as the evidence for absence of bulk superconductivity, where no diamagnetic signal was observed in the T-range of resistivity broadening. Here, however, the small crystal size makes discussion unclear. More detailed measurement, especially magnetization study on larger single crystals has been desired.

Broadening of superconductivity transition is observed in various kinds of superconductors [13,14]. It is usually due to a superconducting fluctuation, derived from a short coherence length (ξ) and a low-dimensionality. If we consider the superconducting parameters of MgB_2 such as the high $T_c \approx 40$ K and the short coherence length $\xi \approx 100$ Å[2,3] together with the anisotropy, it is likely that thermal fluctuation effect manifests itself near T_c. However, to our knowledge, there has been little report on the fluctuation effect in MgB_2, except for two reports [15,16].

In this study we present the superconducting transition behavior of MgB_2 single crystal, via ρ_{ab}, ρ_c and magnetization. The onset temperature T_{on} below which a sign of superconductivity is observed, is well determined in both resistivity and magnetization. The whole data support that the H_{c2} is strongly affected by a thermal fluctuation of superconductivity.

2 Experimental

Single crystals of MgB_2 were grown under high-pressure in Mg-B-N system [2]. Resistivity was measured by a four-probe method. A typical dimension of the samples for in-plane resistivity measurements was $300\times100\times30$ μm^3. The dimension of a crystal for c-axis resistivity measurements was 200×200 μm^2 in the ab-plane and 150 μm along the c-axis. The temperature dependence of ρ_c above T_c is almost the same as that of ρ_{ab}, and the estimated anisotropy

$(\rho_c/\rho_{ab})^{0.5}$ is about 3-7 [8]. Electrical current (I) was changed from 0.05 mA up to 10 mA. A magnetic field up to 12 Tesla (T) was applied both parallel and perpendicular to the c-axis, and resistivity was measured by sweeping the temperature down to 5 K. In magnetization measurement, a commercial SQUID magnetometer (Quantum Design) was used. We have aligned 100 pieces of crystals on a sample holder, in order to gain a magnetization signal. The total weight of the sample was about 0.7 mg. Each crystal consists of a single domain and has a flat ab-surface. Magnetization measurements were carried out in a warming-up T- sweep after zero-field cooling and a cooling-down sweep in a constant magnetic field up to 7 T in both directions parallel and perpendicular to the c-axis. We confirmed no sweep-rate dependence of the magnetization by measuring with a very slow sweep rate of 4 mK/min.

3 Results and discussion

Figure 1(a) shows the in-plane resistivity (ρ_{ab}) in magnetic fields parallel to the c-axis ($H//c$). Although the superconducting transition at $H = 0$ is very sharp, the transition becomes broader with increasing the magnetic field. The resistivity remains finite even at the lowest temperature in high magnetic fields. The c-axis resistivity (ρ_c) also shows a broadened SC transition in $H//c$ (Fig. 1(b)). As is similar to the case of ρ_{ab}, the resistive broadening in ρ_c is enhanced with increasing the magnetic field, and the degree of broadening is very similar to that in ρ_{ab}. On the other hand, the resistive broadening is narrower in fields parallel to the ab-plane ($H//ab$), as is shown in Figs. 2 (a) and (b). For example, the broadening width $\Delta T_c \approx 1$ K at $H(//ab)$=2 T, while $\Delta T_c \approx 7$ K at $H(//c)$=2 T. Even for $H//ab$, resistive broadening is clearly observed at high enough fields. It should be noted that the broadening behavior is very similar in ρ_{ab} and ρ_c. The results in Figs. 1 and 2 suggest that a broadening width in a magnetic field is determined only by the direction of external field, being independent of the current direction. Therefore, the flux creep by a Lorentz force cannot be the origin of resistivity broadening. This broadening nature is reminiscent of the vortex properties in High-T_c cuprate superconductor [17].

In order to examine whether the resistivity drop corresponds to bulk superconductivity or not, we measured magnetization of the aligned mosaic sample. Figure 3(a) shows the magnetization for $H//c$ near T_c. For comparison, the in-plane resistivity (ρ_{ab}) is presented in Fig. 3(b). Broadening of superconductivity transition is observed not only in resistivity but also in magnetization. The onset temperature of magnetization ($T_{on,M}$) is much higher than zero resistivity temperature $T_{0,\rho}$, and comparable to $T_{on,\rho}$. The diamagnetic signal near $T_{on,M}$ and $T_{on,\rho}$ is of the order of 10^{-6} emu for 100 pieces of crystals. If only one piece of crystal were measured, the diamagnetic signal could not be detected in this T-range, since the resolution of the magnetometer is of the order of 10^{-8} emu. The absolute diamagnetic signal from T_{on} to $T_{0,\rho}$ ($|M(T_{on,M}) - M(T_{0,\rho})|/V$) is of the order of 0.1 Gauss/cm^3, on the assumption that a whole volume of the sample (V) contributes to the diamagnetism. The diamagnetic signal above $T_{0,\rho}$ was strongly suppressed with increasing H and eventually became undetectable at $H \geq 4$ T, although resistivity shows a drop as a sign of superconductivity.

Also in $H//ab$, the magnetization shows broadening of SC transition, but with a narrower width than the case of $H//c$ owing to the anisotropy in the superconducting state (Fig. 4). In this field direction, $T_{on,M}$ is nearly equal to $T_{on,\rho}$ but 1∼2 K higher than $T_{0,\rho}$. For a polycrystalline MgB_2 in which crystal axes of grains are randomly oriented, the magnetic properties below T_c is dominated by the $H//ab$ component because of the higher critical field in this field direction. Since a large volume is available for a polycrystalline sample, even a small diamagnetic response can easily be detectable. This is the reason why a good correspondence of the critical field between resistivity and magnetization was reported for polycrystalline MgB_2 [18], whereas a small signal may have been missed in the measurements of single crystal [7,12].

For discussion, it may be useful to examine the other examples of resistive broadening. In high-T_c superconducting cuprate (HTSC), it is widely accepted that H_{c2} is not well defined, owing to a strong thermal fluctuation in comparison to the superconducting condensation energy. As a consequence of fluctuation, vortex liquid state is observed in a wide temperature range. For the case of MgB_2, the coherence length is much shorter than those for conventional superconductors. It leads to weakness of SC for thermal disturbance. The effect of thermal fluctuation on superconductivity is evaluated by the condensation energy E_c per coherence volume V_c, $V_cE_c = \xi_{ab}^2\xi_c N(0)\Delta^2/2$, since nucleation of superconductivity occurs fractionally within this volume near T_c. By using the reported values of ξ_{ab}=68Å, ξ_c=23Å[19], $N(0)$=0.25 states/eV-cell [20], and 2Δ=106 cm^{-1} [21], we obtain $V_cE_c \sim 20$ meV. This is orders of magnitude lower than those of the conventional superconductors. Furthermore, if the smaller gap [22,23,24] is taken into account, V_cE_c related to this gap becomes the same order as k_BT_c=3.4 meV. Therefore, it is likely that superconducting fluctuation effect is prominent in MgB_2, and that the H_{c2} of MgB_2 is not well determined. Here it should be noted that the specific heat [7] and the thermal conductivity [25] for single crystal MgB_2 hardly show a clear superconductivity signal above $T_{0,\rho}$. It suggests that thermodynamical transition temperature is defined at $T_{0,\rho}$ rather than at $T_{on,\rho}$. In this case, T_{on} is the characteristic temperature at which superconducting fluctuation becomes conspicuous.

The degree of fluctuation can be estimated from the criterion $|T_c - T| \leq T_cG_i$, where $G_i = (T_c/H_c^2\xi_c\xi_{ab}^2)/2$ is the Ginzberg number and H_c is thermodynamic critical field [26]. For the present case, the value T_cG_i is much smaller than

10^{-2} K, suggesting a negligible fluctuation effect at zero magnetic field. On the other hand, the situation is different at sufficiently high magnetic field H, where the cyclotron radius of Cooper pair $r_0 = (\phi_0/2\pi H)^{0.5}$ becomes shorter than the coherence length [27]. The critical temperature region in $H//c$ can be estimated as $|T_{cH} - T| \leq (k_B H/\Delta C \phi_0 \xi_c)^{2/3} T_{c0}$, where k_B is the Boltzmann constant, ΔC is specific heat jump, and ϕ_0 is a quantum flux. Since $\xi_{ab} \sim 100$ Å, r_0 becomes shorter than ξ_{ab} at $H \geq 3$ T. With using $\Delta C/k_B$=3.3×10^{20} carriers/cm^3 [28], H=3 T, and $\xi_c = 23$ Å [19], the critical temperature region of 0.6 K is obtained. It is large enough to introduce broadening of the superconducting transition in MgB$_2$. The narrower broadening in $H//ab$ may also be explained by the same model. In $H//ab$, ξ_c should be compared with r_0. Therefore, a larger field H is necessary to manifest fluctuation effect, because $\xi_c < \xi_{ab}$.

The origin of the resistive broadening has been discussed in relation to the non-ohmic behavior [7,10,11,12]. Figure 5 shows an example of resistive broadening, measured with different current densities. In the figure Sample A and Sample B were taken from the same batch, and had been preserved in the same dry box. The only difference between them is the crystal width. Namely the sample dimension perpendicular to the current direction is three times larger in Sample B than in Sample A, which gives a different current density for the same current value. The resistivity curves of these two samples are similar when the current I=8 mA. With decreasing the current, both samples show non-ohmic behavior, but more remarkable change of $\rho(T)$-curve is seen in Sample A than in Sample B. Eventually the $\rho(T)$-curve in sample A shows little change with reducing current. The resistive curves in the low current regime show a clear difference between the samples. In Sample A, the resistivity steeply decreases as the temperature decreases from $T_{on} \approx 27$ K, creating a concave curvature, while a moderate decrease is seen in Sample B. These phenomena strongly suggest that the resistive curves are governed by some surface effect, since a bulk critical behavior should be determined by the current density.

A possible explanation for the above current-dependence is surface superconductivity [7,29]. However, the observed diamagnetic signal in between T_{on} and $T_{0,\rho}$ is too large to be attributed to the surface superconductivity [30,31]. Furthermore, the resistive broadening is observable even in $H//ab$, in which surface superconductivity should be negligible. Therefore we conclude that the resistivity drop in the critical T-region originates from a bulk superconducting fluctuation.

By taking these facts into consideration, we propose a possibility of surface barrier effect [32] for the origin of non-ohmic behavior and the different resistivity curve with low current in Fig. 5. In this case, a substantial current flows on the side-surface of the crystals in a magnetic field because of a high critical current due to the surface barrier. The temperature dependence of resistivity in $H//c$ is determined by the two components, the bulk resistance R_{bulk} and surface barrier resistance R_{sf}, as $1/\rho \sim 1/R_{bulk} + 1/R_{sf}$. Since the side surface area is common for the two crystals, the difference of the current dependence is ascribed to the $1/R_{bulk}$; $1/R_{bulk}$ in Sample A is about three times smaller than that in Sample B due to the three times narrower width in the dimensions. Correspondingly the effect of $1/R_{sf}$ is more obvious in Sample A. Therefore the non-ohmic behavior can be attributed primarily to the change in R_{sf} with the current. On the other hand, the resistive curve for Sample B, in which less contribution of $1/R_{sf}$ is expected, shows a similar convex curvature as seen in $H//ab$ even with the lowest current, which is reminiscent of a sharp decrease of R_{bulk} expected near T_c in a mean-field fluctuation.

Finally we show the magnetic phase diagram for MgB_2 in Fig. 6. Irrespective of the experimental methods, the data points are well on the same curves. Here, $T_{0,M}$ is defined by the maximum of d^2T/dM^2. T_{on} is the characteristic temperature below which superconductivity order parameter develops, while the critical temperature for a bulk superconductivity is close to T_0. Then, the area between $H(T_{on})$ and $H(T_0)$-lines turns out to be the superconducting fluctuation region. In the magnetization, irreversibility temperatures are not well resolved.

It should be noted that, in each direction of magnetic field, the slope of H_{on} is enhanced at higher magnetic fields. This may be ascribed to the increase of superconducting fluctuation, because of the dimensionality change due to the suppression of the 3D-like π-band gap in high magnetic fields.

4 Summary

We report the superconducting transition properties of MgB_2 in magnetic fields. In both resistivity and magnetization, an enhancement of the transition broadening was observed with increasing field. This suggests that the broadening is not due to a surface superconductivity but to a superconducting fluctuation including vortex liquid and/or glass state. The effect of superconducting fluctuation is estimated from the coherence length and the gap energy. We discussed the origin of non-ohmic behavior in $H//c$, by comparing the resistivities for the crystals with different widths in the dimensions. It is most likely that the non-ohmic behavior between $T_{on,\rho}$ and $T_{0,\rho}$ is due to the surface barrier effect.

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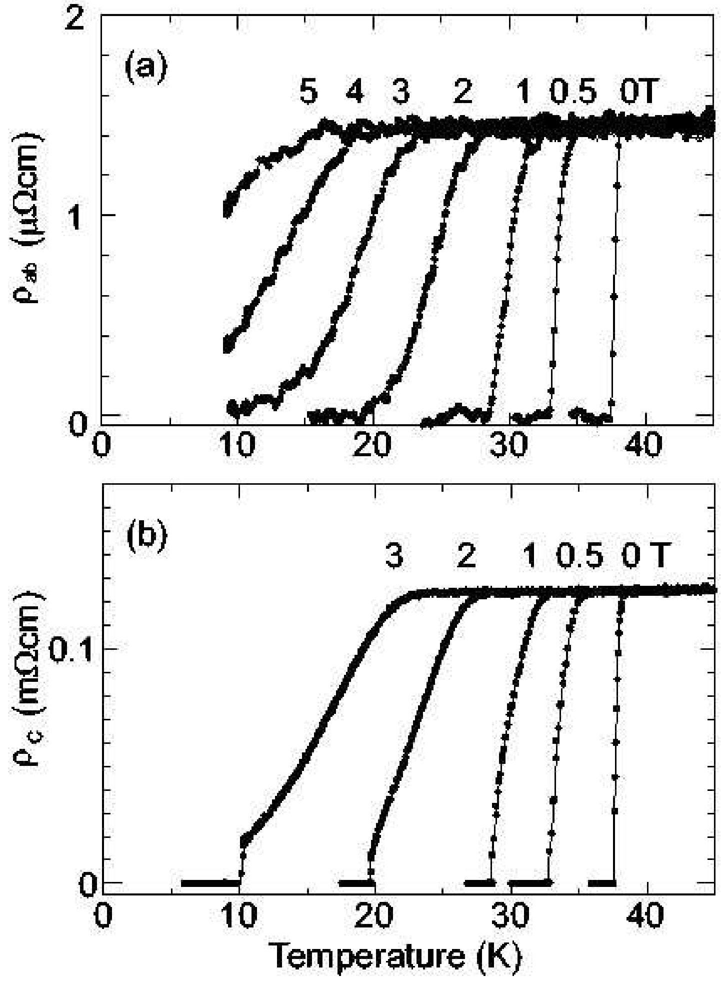

Fig. 1. Resistive broadening in $H//c$ for (a) $I//ab$ and (b) $I//c$. In the measurements, I=1 mA was used.

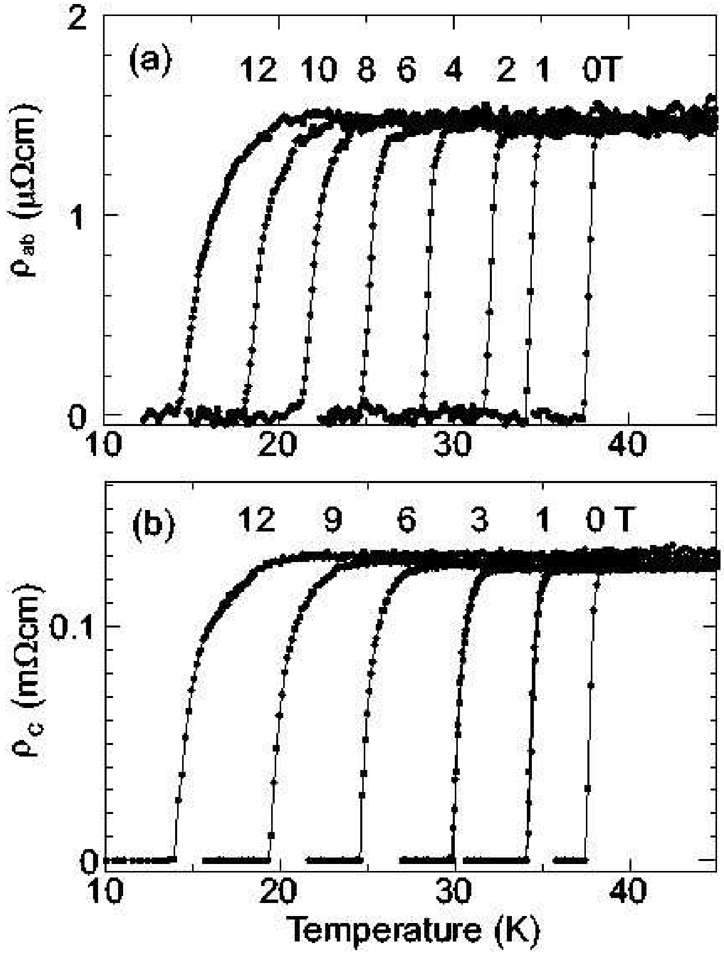

Fig. 2. Resistive broadening in $H//ab$ for (a) $I//H//ab$ and (b) $I//c$. In the measurements, I=1 mA was used.

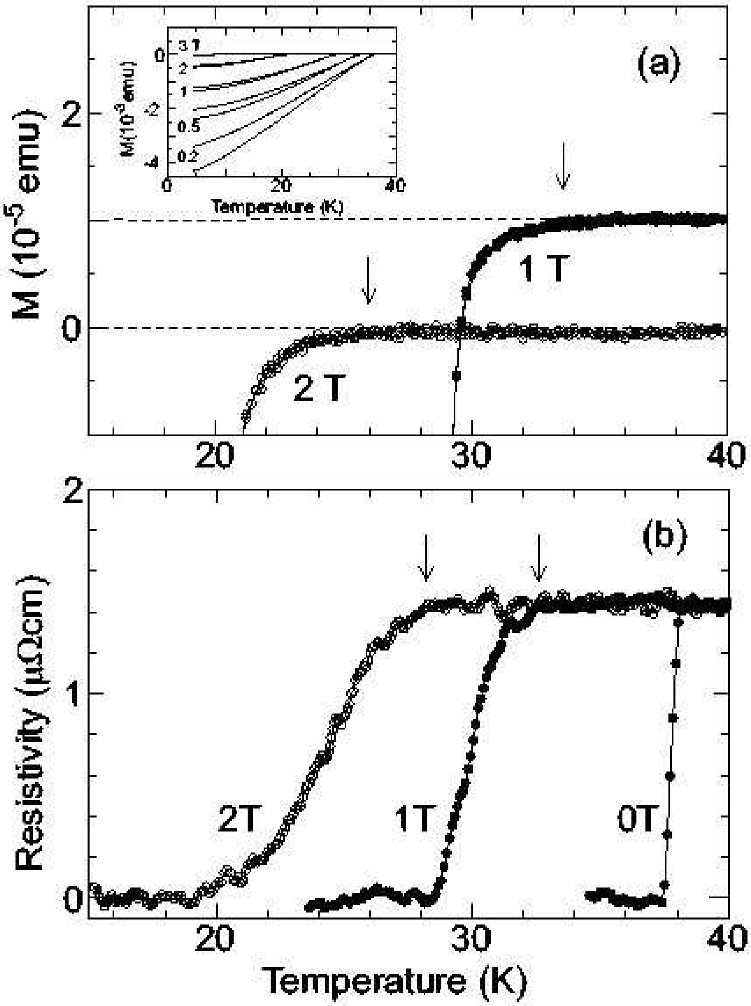

Fig. 3. (a) Temperature dependence of magnetization in $H//c$ around superconductivity transition. The data are intentionally shifted upward. The inset shows magnetization plotted with a larger scale. (b) The resistivity at 1 and 2 T measured with I=1 mA. Arrows indicate onset temperature of superconductivity transition, $T_{on,M}$ or $T_{on,\rho}$.

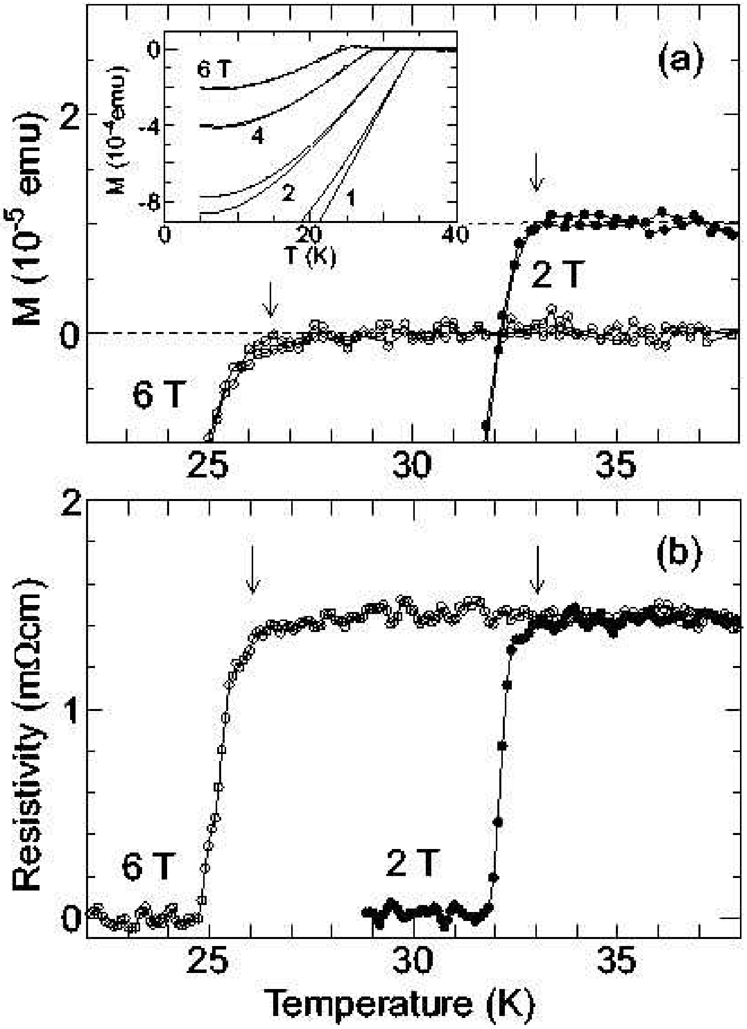

Fig. 4. (a) Temperature dependence of magnetization in $H//ab$ around superconductivity transition. The data are intentionally shifted upward. The inset shows magnetization plotted with a larger scale. (b) The resistivity at 2 and 6 T, measured with I=1 mA. Arrows indicate onset temperature of superconductivity transition, $T_{on,M}$ or $T_{on,\rho}$.

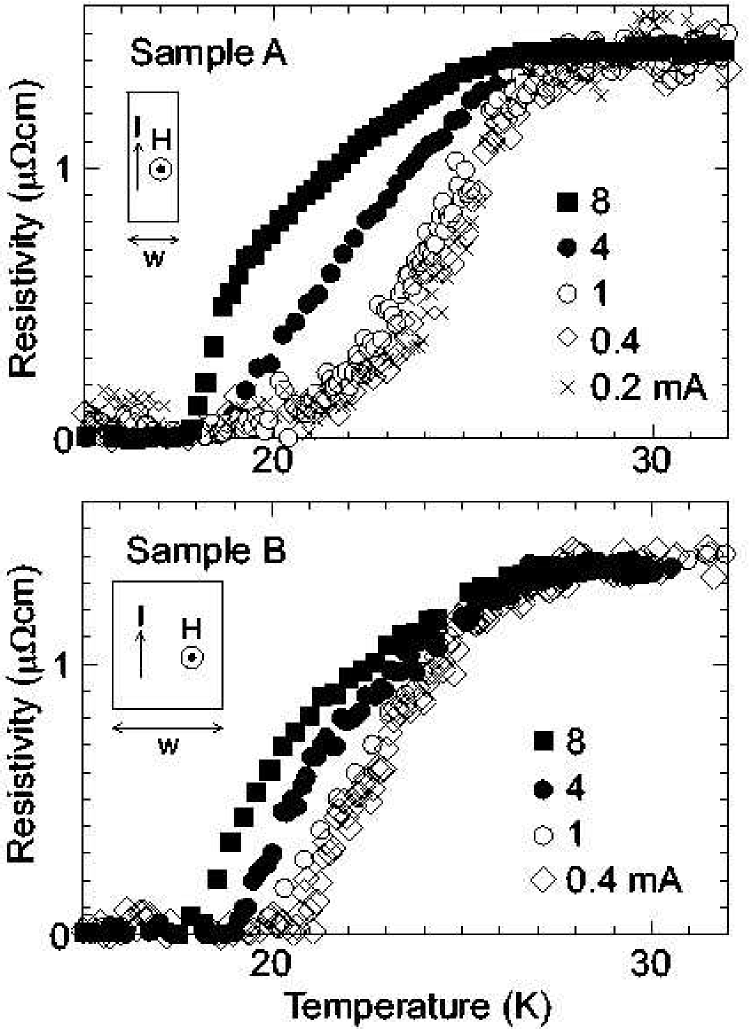

Fig. 5. In-plane resistivity (ρ_{ab}) in H=2 T ($H//c$), measured with different currents for two samples. The dimensions for the samples are as follows. Sample A: The width w=84 μm, and the thickness along the c-axis d=50 μm. Sample B: w=260 μm, d=50 μm. The insets show the schematic view of the sample configuration. The current density for I=1 mA is J=24 A/cm^2 in Sample A and J=7.7 A/cm^2 in Sample B, assuming a uniform current flow in the sample.

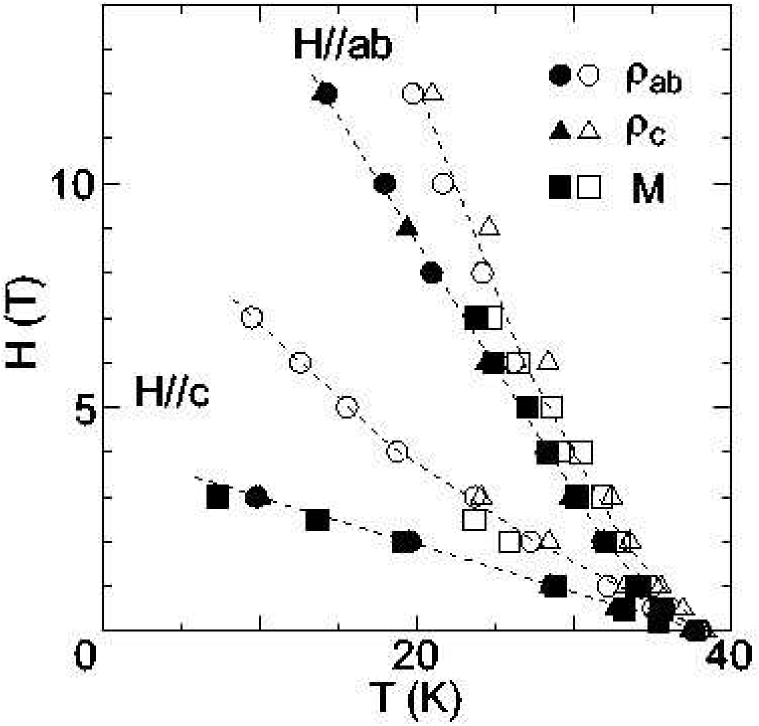

Fig. 6. Critical field in $H//ab$ and $H//c$. Circle, triangle and square represent results obtained from ρ_{ab}, ρ_c, and magnetization M, respectively. Open and closed symbols represent T_{on} and T_0, respectively. T_0 for magnetization was determined by the peak position of d^2M/dT^2. Lines are guides for the eyes.